



Product Summary

BV _{DSS}	Rds(on) (max)	Package	I _{D (MAX)} T _A = +25°C
30V	190mΩ @ V _{GS} = 10V	SOT363	1A
300	$335m\Omega @ V_{GS} = 4.5V$	301303	0.75A

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Power Management Functions
- Load Switch

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
 For Protocol Costs
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

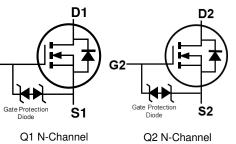
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)

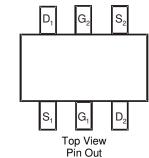




SOT363

Top View





Ordering Information (Note 4)

	Part Number	Case	Packaging				
	DMN3190LDW-7	SOT363	3000/Tape & Reel				
DMN3190LDW-13		SOT363	10000/Tape & Reel				
Notes:	Notes: 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

G1

Marking Information

	D_2	G1		S ₁	
			YN EN		
L	S_2	G_2		D ₁	

N31 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Da	ate Code Key												
	Year	201	1	~		2019	20	020	2021		2022	2	2023
	Code	Y		~		G		H			J		K
	Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
	Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6) Vec. 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	1000 900	mA
Continuous Drain Current (Note 6) V _{GS} = 10V	t < 5s	T _A = +25°C T _A = +70°C	ID	1300 1000	mA
Maximum Continuous Body Diode Forward Current	(Note 5)	I _S	0.5	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	9.6	А		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	0.32	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	395	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	320	°C/W
Thermal Resistance, Junction to Case	•	R _{θJC}	143	0/10
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	-,		- 71-			
Drain-Source Breakdown Voltage	BV _{DSS}	30	_		V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$	IDSS	_	_	1	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	—		±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	1.5		2.8	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	D	_	122	190	mΩ	$V_{GS} = 10V, I_D = 1.3A$
	R _{DS(ON)}	—	181	335	11122	$V_{GS} = 4.5V, I_D = 290mA$
Diode Forward Voltage		—		1.2	V	$V_{GS} = 0V, I_{S} = 250mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	87	_	pF	
Output Capacitance	Coss	—	17	—	pF	V _{DS} = 20V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	12	—	pF	
Gate Resistance	Rg	_	69.8	_	Ω	$f = 1MHz, V_{GS} = 0V, V_{DS} = 0V$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	0.9	—	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	2.0	_	nC	10V/ 100/ 1000 0000
Gate-Source Charge		_	0.3	—	nC	$V_{DS} = 10V, I_D = 250mA$
Gate-Drain Charge	Q _{gd}	_	0.3	_	nC	
Turn-On Delay Time	t _{D(ON)}	_	4.5	_	ns	
Turn-On Rise Time		_	8.9	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time		_	30.3	—	ns	$R_{G} = 10\Omega, I_{D} = 100mA$
Turn-Off Fall Time	t _{D(OFF)} t _F		15.6	_	ns]

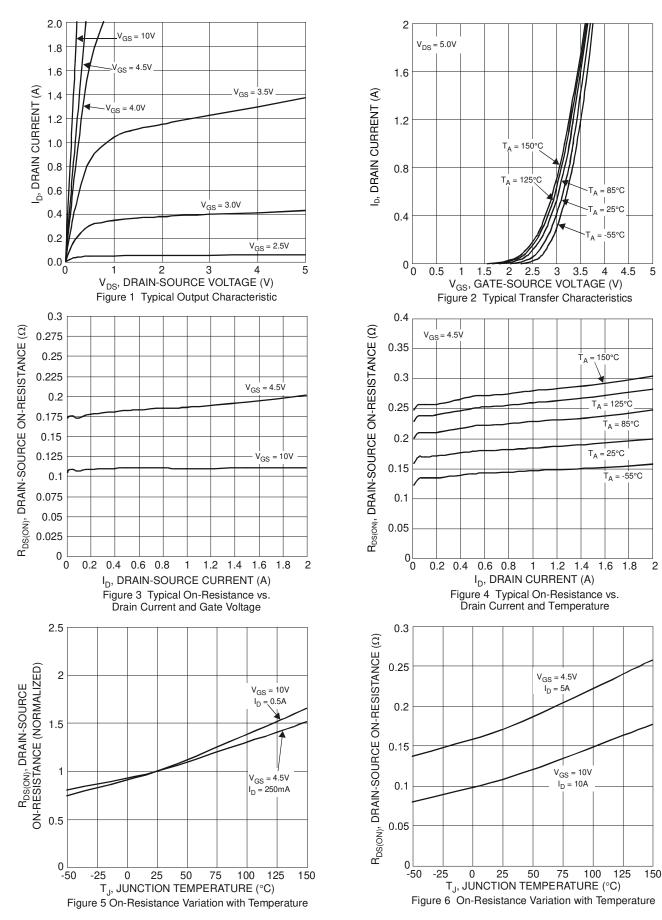
Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

6. Device mounted on $1" \times 1"$ FR-4 PCB with high coverage 2oz. Copper, single sided.

7. Short duration pulse test used to minimize self-heating effect.

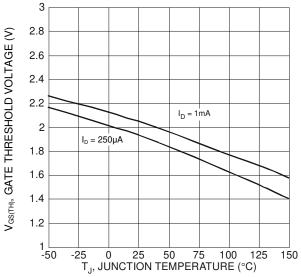
8. Guaranteed by design. Not subject to product testing.

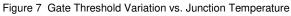


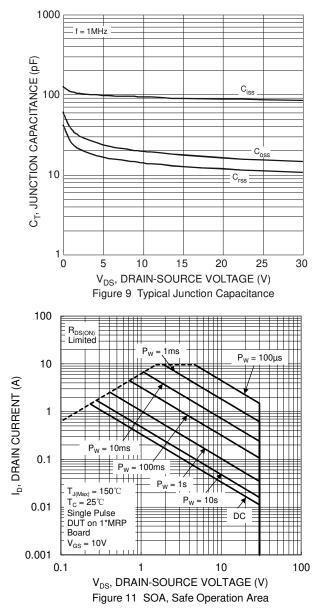


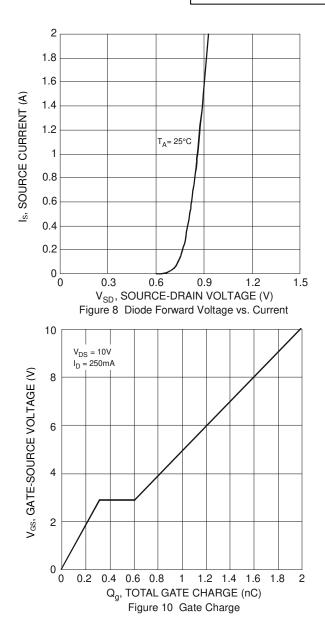


DMN3190LDW







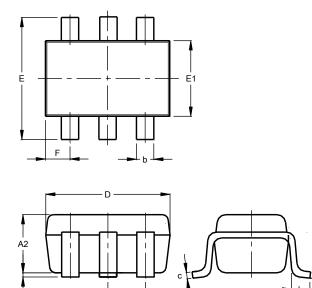




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



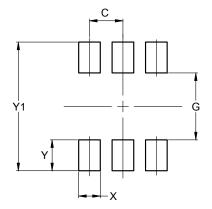
	50	T363	
D :			-
Dim	Min	Max	Тур
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
С	0.10	0.22	0.11
D	1.80	2.20	2.15
Е	2.00	2.20	2.10
E1	1.15	1.35	1.30
е	C).650 E	SC
F	0.40	0.45	0.425
L	0.25	0.40	0.30
а	0°	8°	
All I	Dimen	sions	in mm

Suggested Pad Layout

A1

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500



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